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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M4/M0
Core Size	32-Bit Dual-Core
Speed	204MHz
Connectivity	CANbus, EBI/EMI, I²C, IrDA, Microwire, SD, SPI, SSI, SSP, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I²S, Motor Control PWM, POR, PWM, WDT
Number of I/O	83
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	16K x 8
RAM Size	104K x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 3.6V
Data Converters	A/D 8x10b; D/A 1x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	144-LQFP
Supplier Device Package	144-LQFP (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/lpc4312jbd144e

- Wake-up from Deep-sleep, Power-down, and Deep power-down modes via external interrupts and interrupts generated by battery powered blocks in the RTC power domain.
- Brownout detect with four separate thresholds for interrupt and forced reset.
- Power-On Reset (POR).

- Available as LQFP208, LQFP144, LBGA256, or TFBGA100 packages.

3. Applications

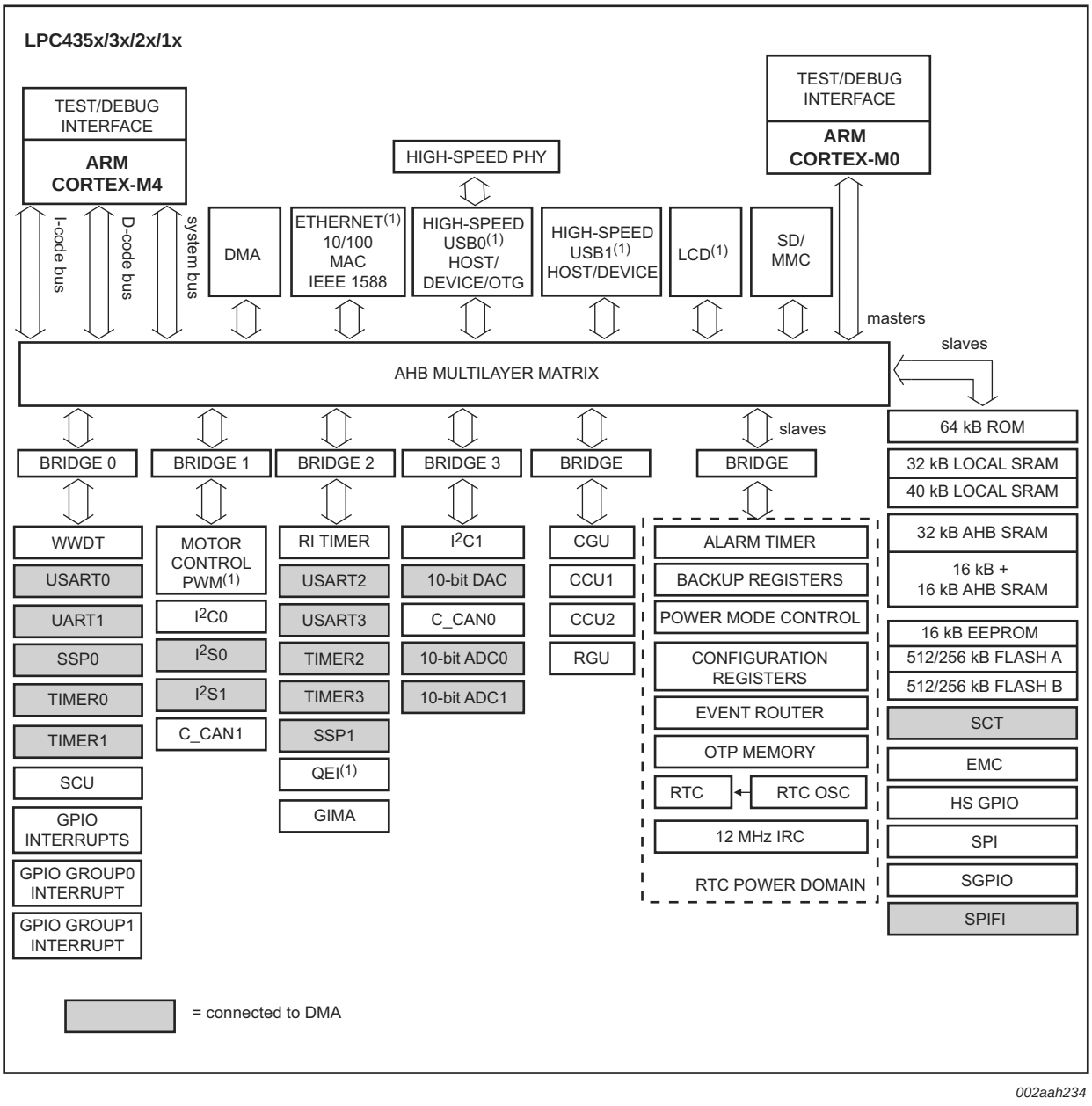
- Motor control
- Power management
- White goods
- RFID readers
- Embedded audio applications
- Industrial automation
- e-metering

4. Ordering information

Table 1. Ordering information

Type number	Package		
	Name	Description	Version
LPC4357FET256	LBGA256	Plastic low profile ball grid array package; 256 balls; body 17 × 17 × 1 mm	SOT740-2
LPC4357JET256	LBGA256	Plastic low profile ball grid array package; 256 balls; body 17 × 17 × 1 mm	SOT740-2
LPC4357JBD208	LQFP208	Plastic low profile quad flat package; 208 leads; body 28 × 28 × 1.4 mm	SOT459-1
LPC4353FET256	LBGA256	Plastic low profile ball grid array package; 256 balls; body 17 × 17 × 1 mm	SOT740-2
LPC4353JET256	LBGA256	Plastic low profile ball grid array package; 256 balls; body 17 × 17 × 1 mm	SOT740-2
LPC4353JBD208	LQFP208	Plastic low profile quad flat package; 208 leads; body 28 × 28 × 1.4 mm	SOT459-1
LPC4337FET256	LBGA256	Plastic low profile ball grid array package; 256 balls; body 17 × 17 × 1 mm	SOT740-2
LPC4337JET256	LBGA256	Plastic low profile ball grid array package; 256 balls; body 17 × 17 × 1 mm	SOT740-2
LPC4337JBD144	LQFP144	Plastic low profile quad flat package; 144 leads; body 20 × 20 × 1.4 mm	SOT486-1
LPC4337JET100	TFBGA100	Plastic thin fine-pitch ball grid array package; 100 balls; body 9 × 9 × 0.7 mm	SOT926-1
LPC4333FET256	LBGA256	Plastic low profile ball grid array package; 256 balls; body 17 × 17 × 1 mm	SOT740-2
LPC4333JET256	LBGA256	Plastic low profile ball grid array package; 256 balls; body 17 × 17 × 1 mm	SOT740-2
LPC4333JBD144	LQFP144	Plastic low profile quad flat package; 144 leads; body 20 × 20 × 1.4 mm	SOT486-1
LPC4333JET100	TFBGA100	Plastic thin fine-pitch ball grid array package; 100 balls; body 9 × 9 × 0.7 mm	SOT926-1
LPC4327JBD144	LQFP144	Plastic low profile quad flat package; 144 leads; body 20 × 20 × 1.4 mm	SOT486-1
LPC4327JET100	TFBGA100	Plastic thin fine-pitch ball grid array package; 100 balls; body 9 × 9 × 0.7 mm	SOT926-1
LPC4325JBD144	LQFP144	Plastic low profile quad flat package; 144 leads; body 20 × 20 × 1.4 mm	SOT486-1
LPC4325JET100	TFBGA100	Plastic thin fine-pitch ball grid array package; 100 balls; body 9 × 9 × 0.7 mm	SOT926-1
LPC4323JBD144	LQFP144	Plastic low profile quad flat package; 144 leads; body 20 × 20 × 1.4 mm	SOT486-1
LPC4323JET100	TFBGA100	Plastic thin fine-pitch ball grid array package; 100 balls; body 9 × 9 × 0.7 mm	SOT926-1
LPC4322JBD144	LQFP144	Plastic low profile quad flat package; 144 leads; body 20 × 20 × 1.4 mm	SOT486-1
LPC4322JET100	TFBGA100	Plastic thin fine-pitch ball grid array package; 100 balls; body 9 × 9 × 0.7 mm	SOT926-1
LPC4317JBD144	LQFP144	Plastic low profile quad flat package; 144 leads; body 20 × 20 × 1.4 mm	SOT486-1
LPC4317JET100	TFBGA100	Plastic thin fine-pitch ball grid array package; 100 balls; body 9 × 9 × 0.7 mm	SOT926-1
LPC4315JBD144	LQFP144	Plastic low profile quad flat package; 144 leads; body 20 × 20 × 1.4 mm	SOT486-1
LPC4315JET100	TFBGA100	Plastic thin fine-pitch ball grid array package; 100 balls; body 9 × 9 × 0.7 mm	SOT926-1
LPC4313JBD144	LQFP144	Plastic low profile quad flat package; 144 leads; body 20 × 20 × 1.4 mm	SOT486-1
LPC4313JET100	TFBGA100	Plastic thin fine-pitch ball grid array package; 100 balls; body 9 × 9 × 0.7 mm	SOT926-1
LPC4312JBD144	LQFP144	Plastic low profile quad flat package; 144 leads; body 20 × 20 × 1.4 mm	SOT486-1
LPC4312JET100	TFBGA100	Plastic thin fine-pitch ball grid array package; 100 balls; body 9 × 9 × 0.7 mm	SOT926-1

5. Block diagram



(1) Not available on all parts. See Table 2.

Fig 1. LPC435x/3x/2x/1x Block diagram

6.2 Pin description

On the LPC435x/3x/2x/1x, digital pins are grouped into 16 ports, named P0 to P9 and PA to PF, with up to 20 pins used per port. Each digital pin can support up to eight different digital functions, including General Purpose I/O (GPIO), selectable through the System Configuration Unit (SCU) registers. The pin name is not indicative of the GPIO port assigned to it.

The parts contain two 10-bit ADCs (ADC0 and ADC1). The input channels of ADC0 and ADC1 on dedicated pins and multiplexed pins are combined in such a way that all channel 0 inputs (named ADC0_0 and ADC1_0) are tied together and connected to both, channel 0 on ADC0 and channel 0 on ADC1, channel 1 inputs (named ADC0_1 and ADC1_1) are tied together and connected to channel 1 on ADC0 and ADC1, and so forth. There are eight ADC channels total for the two ADCs.

Table 3. Pin description *…continued*

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
P5_0	N3	-	53	37	[2]	N; PU	I/O	**GPIO2[9] —** General purpose digital input/output pin.
							O	**MCOB2 —** Motor control PWM channel 2, output B.
							I/O	**EMC_D12 —** External memory data line 12.
							-	**R —** Function reserved.
							I	**U1_DSR —** Data Set Ready input for UART 1.
							I	**T1_CAP0 —** Capture input 0 of timer 1.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P5_1	P3	-	55	39	[2]	N; PU	I/O	**GPIO2[10] —** General purpose digital input/output pin.
							I	**MCI2 —** Motor control PWM channel 2, input.
							I/O	**EMC_D13 —** External memory data line 13.
							-	**R —** Function reserved.
							O	**U1_DTR —** Data Terminal Ready output for UART 1. Can also be configured to be an RS-485/EIA-485 output enable signal for UART 1.
							I	**T1_CAP1 —** Capture input 1 of timer 1.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P5_2	R4	-	63	46	[2]	N; PU	I/O	**GPIO2[11] —** General purpose digital input/output pin.
							I	**MCI1 —** Motor control PWM channel 1, input.
							I/O	**EMC_D14 —** External memory data line 14.
							-	**R —** Function reserved.
							O	**U1_RTS —** Request to Send output for UART 1. Can also be configured to be an RS-485/EIA-485 output enable signal for UART 1.
							I	**T1_CAP2 —** Capture input 2 of timer 1.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P5_3	T8	-	76	54	[2]	N; PU	I/O	**GPIO2[12] —** General purpose digital input/output pin.
							I	**MCI0 —** Motor control PWM channel 0, input.
							I/O	**EMC_D15 —** External memory data line 15.
							-	**R —** Function reserved.
							I	**U1_RI —** Ring Indicator input for UART 1.
							I	**T1_CAP3 —** Capture input 3 of timer 1.
							-	**R —** Function reserved.
							-	**R —** Function reserved.

Table 3. Pin description *…continued*

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
P6_3	P15	-	113	79	[2]	N; PU	I/O	**GPIO3[2] —** General purpose digital input/output pin.
							O	**USB0_PPWR —** VBUS drive signal (towards external charge pump or power management unit); indicates that the VBUS signal must be driven (active HIGH). Add a pull-down resistor to disable the power switch at reset. This signal has opposite polarity compared to the USB_PPWR used on other NXP LPC parts.
							I/O	**SGPIO4 —** General purpose digital input/output pin.
							O	**EMC_CS1 —** LOW active Chip Select 1 signal.
							-	**R —** Function reserved.
							I	**T2_CAP2 —** Capture input 2 of timer 2.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P6_4	R16	F6	114	80	[2]	N; PU	I/O	**GPIO3[3] —** General purpose digital input/output pin.
							I	**CTIN_6 —** SCT input 6. Capture input 1 of timer 3.
							O	**U0_TXD —** Transmitter output for USART0.
							O	**EMC_CAS —** LOW active SDRAM Column Address Strobe.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P6_5	P16	F9	117	82	[2]	N; PU	I/O	**GPIO3[4] —** General purpose digital input/output pin.
							O	**CTOUT_6 —** SCT output 6. Match output 2 of timer 1.
							I	**U0_RXD —** Receiver input for USART0.
							O	**EMC_RAS —** LOW active SDRAM Row Address Strobe.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P6_6	L14	-	119	83	[2]	N; PU	I/O	**GPIO0[5] —** General purpose digital input/output pin.
							O	**EMC_BLS1 —** LOW active Byte Lane select signal 1.
							I/O	**SGPIO5 —** General purpose digital input/output pin.
							I	**USB0_PWR_FAULT —** Port power fault signal indicating overcurrent condition; this signal monitors over-current on the USB bus (external circuitry required to detect over-current condition).
							-	**R —** Function reserved.
							I	**T2_CAP3 —** Capture input 3 of timer 2.
							-	**R —** Function reserved.
							-	**R —** Function reserved.

Table 3. Pin description *…continued*

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
PD_11	N9	-	88	-	[2]	N; PU	-	**R —** Function reserved.
							-	**R —** Function reserved.
							O	**$\overline{\text{EMC\_CS3}}$ —** LOW active Chip Select 3 signal.
							-	**R —** Function reserved.
							I/O	**GPIO6[25] —** General purpose digital input/output pin.
							I/O	**USB1_ULPI_D0 —** ULPI link bidirectional data line 0.
							O	**CTOUT_14 —** SCT output 14. Match output 2 of timer 3.
							-	**R —** Function reserved.
PD_12	N11	-	94	-	[2]	N; PU	-	**R —** Function reserved.
							-	**R —** Function reserved.
							O	**$\overline{\text{EMC\_CS2}}$ —** LOW active Chip Select 2 signal.
							-	**R —** Function reserved.
							I/O	**GPIO6[26] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							O	**CTOUT_10 —** SCT output 10. Match output 3 of timer 3.
							-	**R —** Function reserved.
PD_13	T14	-	97	-	[2]	N; PU	-	**R —** Function reserved.
							I	**CTIN_0 —** SCT input 0. Capture input 0 of timer 0, 1, 2, 3.
							O	**$\overline{\text{EMC\_BLS2}}$ —** LOW active Byte Lane select signal 2.
							-	**R —** Function reserved.
							I/O	**GPIO6[27] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							O	**CTOUT_13 —** SCT output 13. Match output 3 of timer 3.
							-	**R —** Function reserved.
PD_14	R13	-	99	-	[2]	N; PU	-	**R —** Function reserved.
							-	**R —** Function reserved.
							O	**$\overline{\text{EMC\_DYCS2}}$ —** SDRAM chip select 2.
							-	**R —** Function reserved.
							I/O	**GPIO6[28] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							O	**CTOUT_11 —** SCT output 11. Match output 3 of timer 2.
							-	**R —** Function reserved.

- Each slice has a 32-bit pattern match filter.

7.18 AHB peripherals

7.18.1 General Purpose DMA

The DMA controller allows peripheral-to memory, memory-to-peripheral, peripheral-to-peripheral, and memory-to-memory transactions. Each DMA stream provides unidirectional serial DMA transfers for a single source and destination. For example, a bidirectional port requires one stream for transmit and one for receives. The source and destination areas can each be either a memory region or a peripheral for master 1, but only memory for master 0.

7.18.1.1 Features

- Eight DMA channels. Each channel can support a unidirectional transfer.
- 16 DMA request lines.
- Single DMA and burst DMA request signals. Each peripheral connected to the DMA Controller can assert either a burst DMA request or a single DMA request. The DMA burst size is set by programming the DMA Controller.
- Memory-to-memory, memory-to-peripheral, peripheral-to-memory, and peripheral-to-peripheral transfers are supported.
- Scatter or gather DMA is supported through the use of linked lists. This means that the source and destination areas do not have to occupy contiguous areas of memory.
- Hardware DMA channel priority.
- AHB slave DMA programming interface. The DMA Controller is programmed by writing to the DMA control registers over the AHB slave interface.
- Two AHB bus masters for transferring data. These interfaces transfer data when a DMA request goes active. Master 1 can access memories and peripherals, master 0 can access memories only.
- 32-bit AHB master bus width.
- Incrementing or non-incrementing addressing for source and destination.
- Programmable DMA burst size. The DMA burst size can be programmed to more efficiently transfer data.
- Internal four-word FIFO per channel.
- Supports 8, 16, and 32-bit wide transactions.
- Big-endian and little-endian support. The DMA Controller defaults to little-endian mode on reset.
- An interrupt to the processor can be generated on a DMA completion or when a DMA error has occurred.
- Raw interrupt status. The DMA error and DMA count raw interrupt status can be read prior to masking.

7.18.2 SPI Flash Interface (SPIFI)

The SPI Flash Interface allows low-cost serial flash memories to be connected to the ARM Cortex-M4 processor with little performance penalty compared to parallel flash devices with higher pin count.

7.23.7 System PLL1

The PLL1 accepts an input clock frequency from an external oscillator in the range of 1 MHz to 25 MHz. The input frequency is multiplied up to a high frequency with a Current Controlled Oscillator (CCO). The multiplier can be an integer value from 1 to 32. The CCO operates in the range of 156 MHz to 320 MHz. This range is possible through an additional divider in the loop to keep the CCO within its frequency range while the PLL is providing the desired output frequency. The output divider can be set to divide by 2, 4, 8, or 16 to produce the output clock. Since the minimum output divider value is 2, it is insured that the PLL output has a 50 % duty cycle. The PLL is turned off and bypassed following a chip reset. After reset, software can enable the PLL. The program must configure and activate the PLL, wait for the PLL to lock, and then connect to the PLL as a clock source. The PLL settling time is 100 μs.

7.23.8 Reset Generation Unit (RGU)

The RGU allows generation of independent reset signals for individual blocks and peripherals on the LPC435x/3x/2x/1x.

7.23.9 Power Management Controller (PMC)

The PMC controls the power to the cores, peripherals, and memories.

The LPC435x/3x/2x/1x support the following power modes in order from highest to lowest power consumption:

1. Active mode
2. Sleep mode
3. Power-down modes:
   a. Deep-sleep mode
   b. Power-down mode
   c. Deep power-down mode

Active mode and sleep mode apply to the state of the core. In a dual-core system, either core can be in active or sleep mode independently of the other core.

If the core is in Active mode, it is fully operational and can access peripherals and memories as configured by software. If the core is in Sleep mode, it receives no clocks, but peripherals and memories remain running.

Either core can enter sleep mode from active mode independently of the other core and while the other core remains in active mode or is in sleep mode.

Power-down modes apply to the entire system. In the Power-down modes, both cores and all peripherals except for peripherals in the always-on power domain are shut down. Memories can remain powered for retaining memory contents as defined by the individual power-down mode.

Either core in active mode can put the part into one of the three power down modes if the core is enabled to do so. If both cores are enabled for putting the system into power-down, then the system enters power-down only once both cores have received a WFI or WFE instruction.

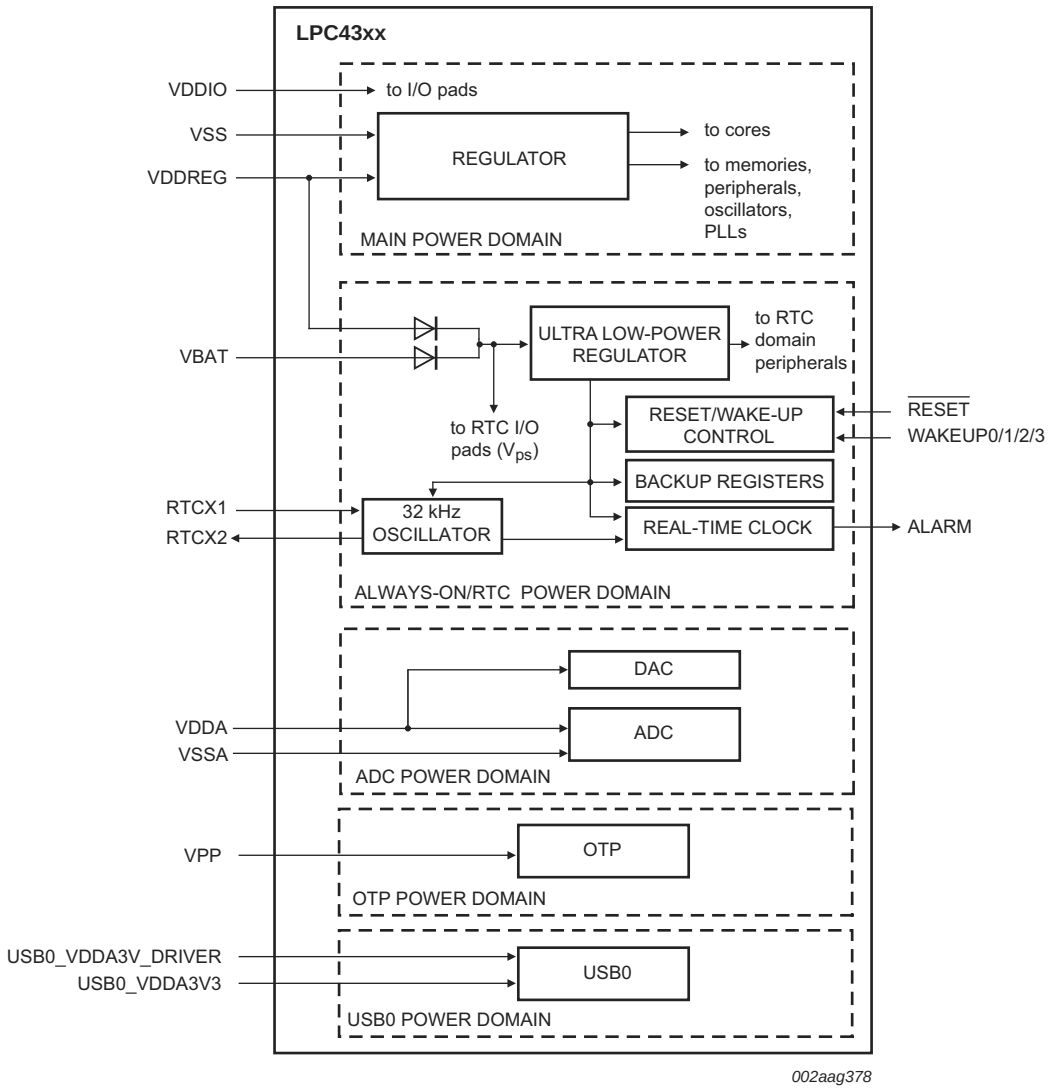


Fig 9. Power domains

7.23.11 Code security (Code Read Protection - CRP)

CRP enables different levels of security so that access to the on-chip flash and use of the JTAG and ISP can be restricted. CRP is invoked by programming a specific pattern into a dedicated flash location. IAP commands are not affected by CRP.

9. Thermal characteristics

The average chip junction temperature, T_j (°C), can be calculated using the following equation:

$$T_j = T_{amb} + (P_D \times R_{th(j-a)}) \quad (1)$$

- T_{amb} = ambient temperature (°C),
- $R_{th(j-a)}$ = the package junction-to-ambient thermal resistance (°C/W)
- P_D = sum of internal and I/O power dissipation

The internal power dissipation is the product of I_{DD} and V_{DD}. The I/O power dissipation of the I/O pins is often small and many times can be negligible. However it can be significant in some applications.

Table 8. Thermal characteristics

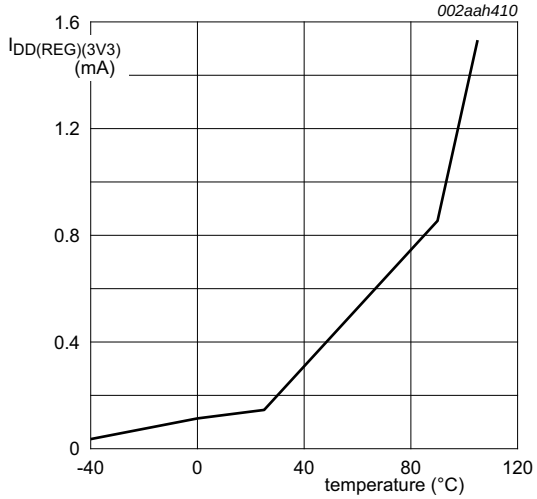
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{j(max)}$	maximum junction temperature	-	-	-	125	°C

Table 9. Thermal resistance (LQFP packages)

Symbol	Parameter	Conditions	Thermal resistance in °C/W ±15 %	
			LQFP144	LQFP208
$R_{th(j-a)}$	thermal resistance from junction to ambient	JEDEC (4.5 in × 4 in); still air	38	31
		Single-layer (4.5 in × 3 in); still air	50	39
$R_{th(j-c)}$	thermal resistance from junction to case	-	11	10

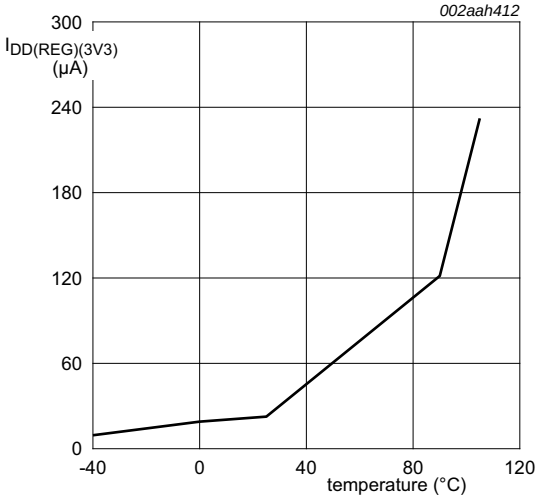
Table 10. Thermal resistance value (BGA packages)

Symbol	Parameter	Conditions	Thermal resistance in °C/W ±15 %	
			LBGA256	TFBGA100
$R_{th(j-a)}$	thermal resistance from junction to ambient	JEDEC (4.5 in × 4 in); still air	29	46
		8-layer (4.5 in × 3 in); still air	24	37
$R_{th(j-c)}$	thermal resistance from junction to case		14	11



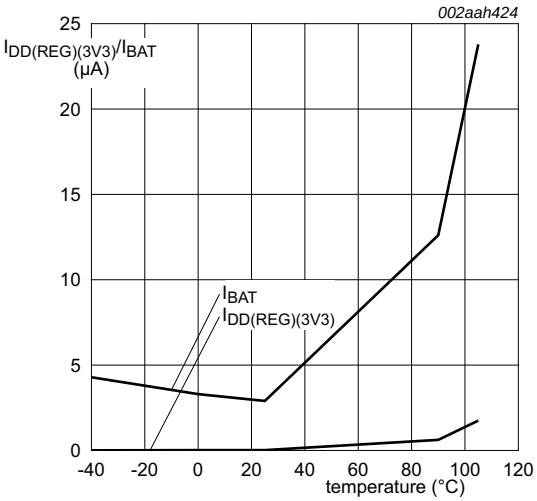
Conditions: $V_{DD(REG)(3V3)} = V_{DD(IO)} = 3.3$ V.

Fig 15. Typical supply current versus temperature in Deep-sleep mode



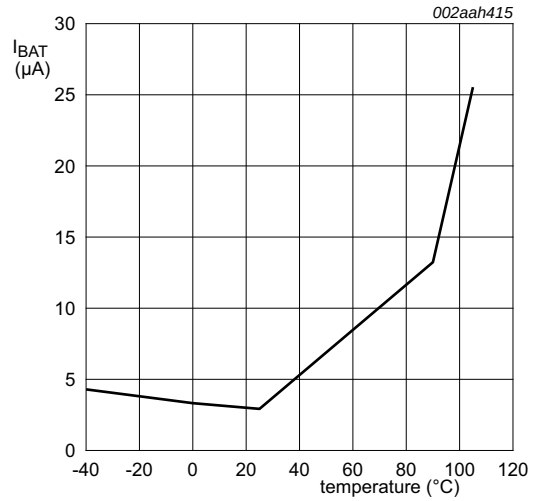
Conditions: $V_{DD(REG)(3V3)} = V_{DD(IO)} = 3.3$ V.

Fig 16. Typical supply current versus temperature in Power-down mode



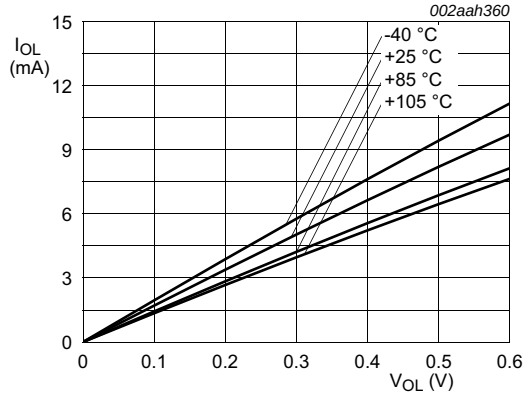
Conditions: $V_{DD(REG)(3V3)} = V_{DD(IO)} = 3.3$ V. $V_{BAT} = V_{DD(REG)(3V3)} + 0.4$ V.

Fig 17. Typical supply current versus temperature in Deep power-down mode

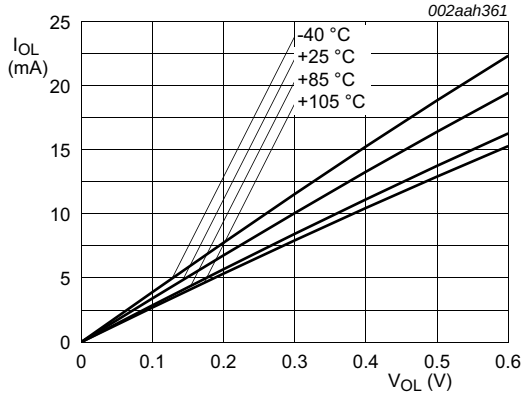


Conditions: $V_{BAT} = 3.6$ V. $V_{DD(REG)(3V3)}$ not present.

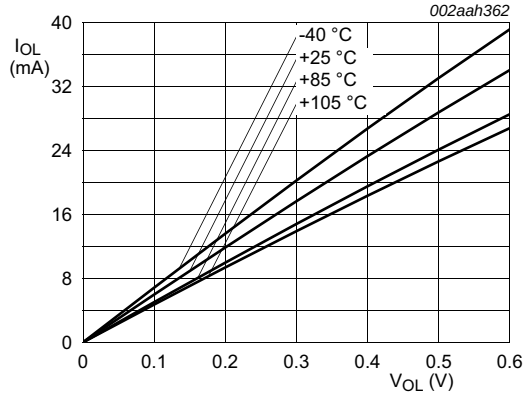
Fig 18. Typical battery supply current versus temperature



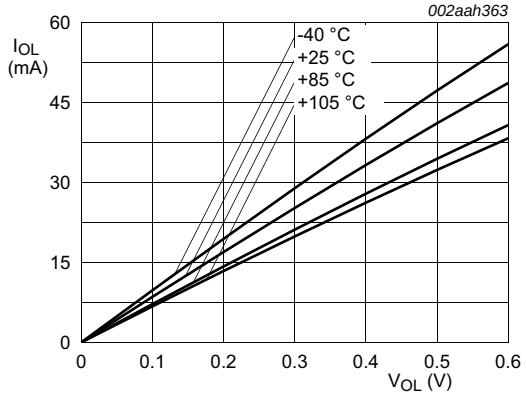
Conditions: $V_{DD(REG)(3V3)} = V_{DD(IO)} = 3.3$ V; normal-drive; EHD = 0x0.



Conditions: $V_{DD(REG)(3V3)} = V_{DD(IO)} = 3.3$ V; medium-drive; EHD = 0x1.



Conditions: $V_{DD(REG)(3V3)} = V_{DD(IO)} = 3.3$ V; high-drive; EHD = 0x2.



Conditions: $V_{DD(REG)(3V3)} = V_{DD(IO)} = 3.3$ V; ultra high-drive; EHD = 0x3.

Fig 22. High-drive pins; typical LOW level output current I_{OL} versus LOW level output voltage V_{OL}

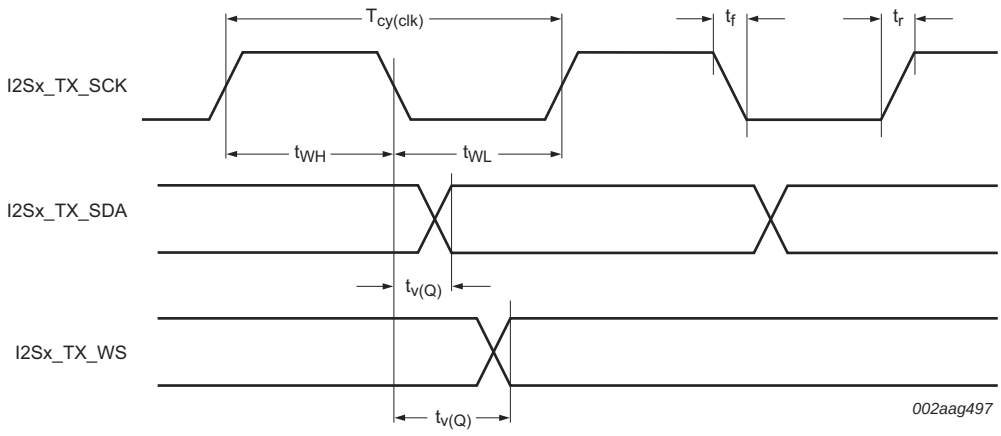


Fig 28. I²S-bus timing (transmit)

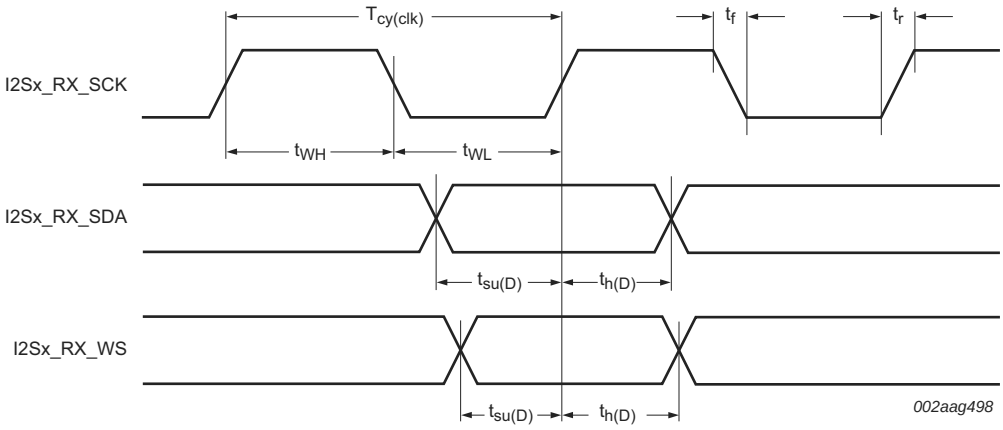


Fig 29. I²S-bus timing (receive)

11.11 USART interface

Table 26. USART dynamic characteristics

T_{amb} = −40 °C to 105 °C; 2.4 V ≤ $V_{DD(REG)(3V3)}$ ≤ 3.6 V; 2.7 V ≤ $V_{DD(IO)}$ ≤ 3.6 V; C_L = 20 pF. sampled at 10 % and 90 % of the signal level; EHS = 1 for all pins. Simulated values.

Symbol	Parameter	Min	Max	Unit
USART master (in synchronous mode)				
$t_{su(D)}$	data input set-up time	26.6	-	ns
$t_{h(D)}$	data input hold time	0	-	ns
$t_{v(Q)}$	data output valid time	0	10.4	ns
USART slave (in synchronous mode)				
$t_{su(D)}$	data input set-up time	2.4	-	ns
$t_{h(D)}$	data input hold time	0	-	ns
$t_{v(Q)}$	data output valid time	4.3	24.3	ns

11.12 SSP interface

Table 27. Dynamic characteristics: SSP pins in SPI mode

T_{amb} = −40 °C to +105 °C; 2.4 V ≤ $V_{DD(REG)(3V3)}$ ≤ 3.6 V; 2.7 V ≤ $V_{DD(IO)}$ ≤ 3.6 V; C_L = 20 pF; sampled at 10 % and 90 % of the signal level; EHS = 1 for all pins. Simulated values.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
SSP master							
$T_{cy(clk)}$	clock cycle time	full-duplex mode	[1]	$1/(25.5 \times 10^6)$	-	-	s
		when only transmitting		$1/(51 \times 10^6)$	-	-	s
t_{DS}	data set-up time	in SPI mode		12.2	-	-	ns
t_{DH}	data hold time	in SPI mode		−3.6	-	-	ns
$t_{v(Q)}$	data output valid time	in SPI mode		-	-	6.7	ns
$t_{h(Q)}$	data output hold time	in SPI mode		−1.7	-	-	ns
t_{lead}	lead time	continuous transfer mode SPI mode; CPOL = 0; CPHA = 0		$T_{cy(clk)}$ + 3.3	-	$T_{cy(clk)}$ + 8.2	ns
		SPI mode; CPOL = 0; CPHA = 1		$0.5 \times T_{cy(clk)}$ + 3.3	-	$0.5 \times T_{cy(clk)}$ + 8.2	ns
		SPI mode; CPOL = 1; CPHA = 0		$T_{cy(clk)}$ + 3.3	-	$T_{cy(clk)}$ + 8.2	ns
		SPI mode; CPOL = 1; CPHA = 1		$0.5 \times T_{cy(clk)}$ + 3.3	-	$0.5 \times T_{cy(clk)}$ + 8.2	ns
		synchronous serial frame mode		$0.5 \times T_{cy(clk)}$ + 3.3	-	$0.5 \times T_{cy(clk)}$ + 8.2	ns
		microwire frame format		$T_{cy(clk)}$ + 3.3	-	$T_{cy(clk)}$ + 8.2	ns
t_{lag}	lag time	continuous transfer mode SPI mode; CPOL = 0; CPHA = 0		$0.5 \times T_{cy(clk)}$	-	-	ns
		SPI mode; CPOL = 0; CPHA = 1		$T_{cy(clk)}$	-	-	ns
		SPI mode; CPOL = 1; CPHA = 0		$0.5 \times T_{cy(clk)}$	-	-	ns
		SPI mode; CPOL = 1; CPHA = 1		$T_{cy(clk)}$	-	-	ns
		synchronous serial frame mode		$T_{cy(clk)}$	-	-	ns
		microwire frame format		$0.5 \times T_{cy(clk)}$	-	-	ns

Table 30. Dynamic characteristics: SGPIO

T_{amb} = −40 °C to +105 °C; 2.4 V ≤ $V_{DD(REG)(3V3)}$ ≤ 3.6 V; 2.7 V ≤ $V_{DD(IO)}$ ≤ 3.6 V. Simulated values.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$t_{su(D)}$	data input set-up time			2	-	-	ns
$t_{h(D)}$	data input hold time		[1]	T_{SGPIO} + 2	-	-	ns
$t_{su(D)}$	data input set-up time	sampled by SGPIO_CLOCK	[1]	T_{SGPIO} + 2	-	-	ns
$t_{h(D)}$	data input hold time	sampled by SGPIO_CLOCK	[1]	T_{SGPIO} + 2	-	-	ns
$t_{v(Q)}$	data output valid time		[1]	-	-	2 × T_{SGPIO}	ns
$t_{h(Q)}$	data output hold time		[1]	T_{SGPIO}	-		ns
$t_{v(Q)}$	data output valid time	sampled by SGPIO_CLOCK	[1]	-3	-	3	ns
$t_{h(Q)}$	data output hold time	sampled by SGPIO_CLOCK	[1]	-3	-	3	ns

[1] SGPIO_CLOCK is the internally generated SGPIO clock. $T_{SGPIO} = 1/f_{SGPIO\_CLOCK}$.

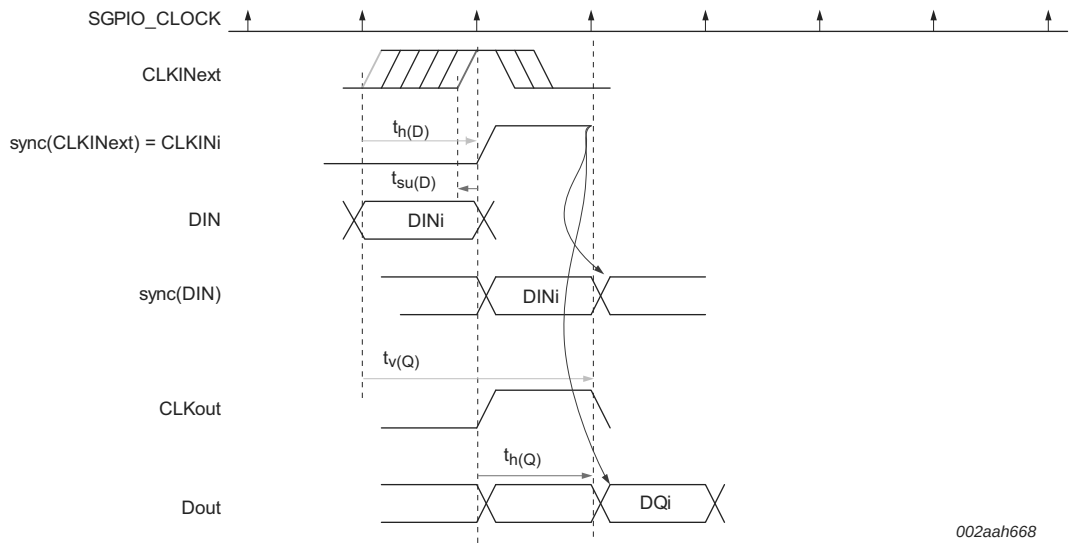
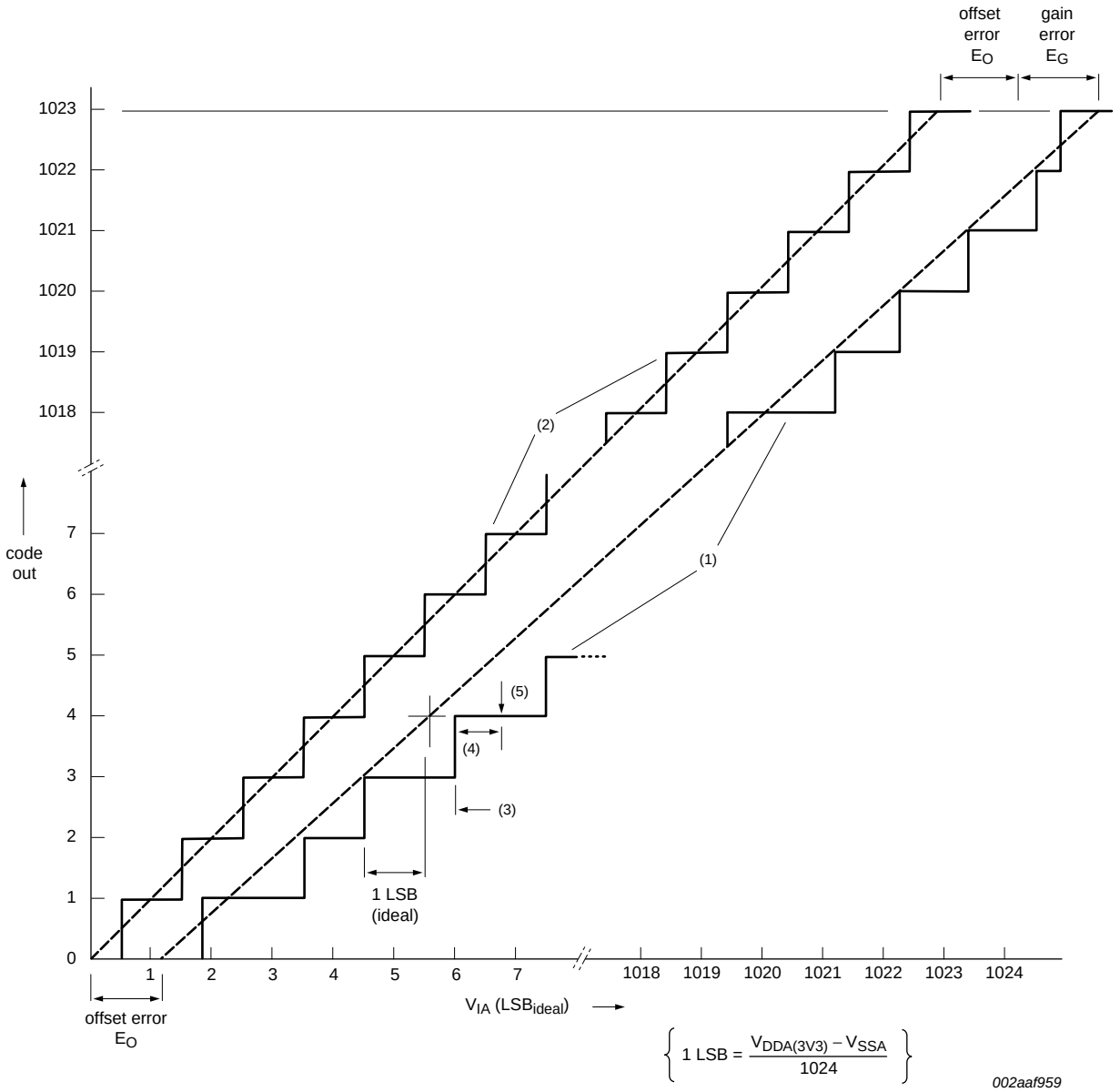


Fig 34. SGPIO timing



(1) Example of an actual transfer curve.

(2) The ideal transfer curve.

(3) Differential linearity error (E_D).

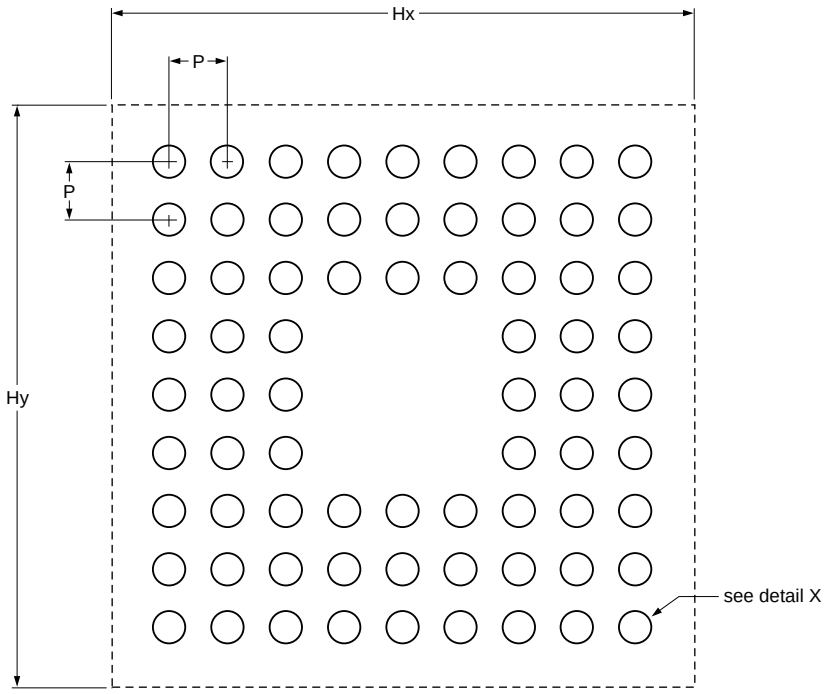
(4) Integral non-linearity ($E_{L(adj)}$).

(5) Center of a step of the actual transfer curve.

Fig 41. 10-bit ADC characteristics

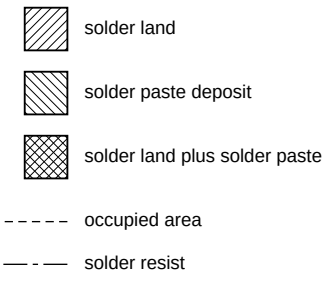
15. Soldering

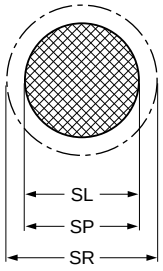
Footprint information for reflow soldering of LBGA256 package **SOT740-2**



Generic footprint pattern

Refer to the package outline drawing for actual layout





detail X

DIMENSIONS in mm

P	SL	SP	SR	Hx	Hy
1.00	0.450	0.450	0.600	17.500	17.500

sot740-2_fr

Fig 55. Reflow soldering of the LBGA256 package

Table 47. Revision history *…continued*

Document ID	Release date	Data sheet status	Change notice	Supersedes
Modifications:	• Updated Section 1 “General description”. • Minimum operating voltage changed from 2.2 V to 2.4 V for $V_{DD(REG)(3V3)}$, $V_{DD(IO)}$, $V_{DDA(3V3)}$, V_{BAT} in Table 11. • Operating temperature corrected in Table 27. Tamb = T_{amb} = -40 °C to 105 °C. • Max and min values of parameters t_{lag} and t_{lead} corrected for SSP master mode in Table 27. • Figure 32 “SSP in SPI mode and SPI slave timing” updated. • Typical values for parameters t_{DS}, t_{DH}, $t_{v(Q)}$, $t_{h(Q)}$ for SSP slave mode replaced by min and max numbers in Table 25. • Parameters t_{lead}, t_{lag}, and t_d added to SSP slave mode in Table 27. • SPIFI timing data restated for CL = 20 pF in Table 29 “Dynamic characteristics: SPIFI”. • USART timing added for master and slave mode in Figure 30 “USART timing”. • USB0_VBUS changed to input only. See Table 3 “Pin description”. • Changed the flash erase time (t_{er}) to 100ms. See Table 15. • Updated Dynamic characteristics: SD/MMC table. See Table 37. • Added Band gap characteristics table. See Table 14. • Updated Table 2: Motor control PWM instead of PWM. • Updated Dynamic characteristics: USB0 and USB1 pins (full-speed). See Table 34. • Added a table note: The values in the table have been calculated with WAITTURN = 0x0 in STATICWAITTURN register. See Table 31. • Added a remark to Table 34. • Updated Table 13 “BOD static characteristics[1]”. Removed BOD interrupt levels 0 and 1; removed Reset levels 0 and 1. Not applicable.			
LPC435X_3X_2X_1X v.4	20140819	Product data sheet	-	LPC435X_3X_2X_1X v.3

19. Legal information

19.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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